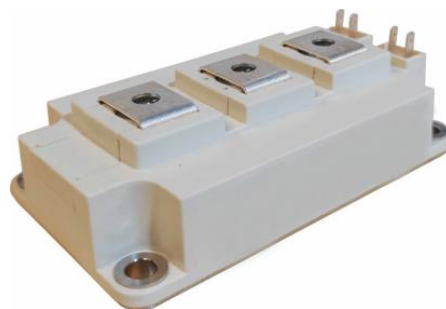


### Electrical Features

- Trench/Fieldstop IGBT
- Half-bridge
- Standard package
- High short circuit capability
- Including anti-parallel FWD



### Typical Applications

- Motor Drives
- Servo Drives
- UPS System
- High Power Converters
- Wind Turbines

### IGBT, Inverter

Maximum Rated Values							
Symbol	Item	Conditions	Rating			Unit	
IGBT							
$V_{CES}$	Collector-emitter voltage	$T_{vj}=25^{\circ}\text{C}$	1200			V	
$V_{GES}$	Gate-emitter voltage	-	$\pm 20$			V	
$I_C$	Collector current,DC	$T_C=100^{\circ}\text{C}, T_{vj}=175^{\circ}\text{C}$	450			A	
$I_{CRM}$	Repetitive peak collector current	$t_p=1\text{ms}$	900			A	
$t_{SC}$	Short circuit withstand time	$V_{GE}=15\text{V}, V_{CC}=600\text{V}, T_{vj}\leq 150^{\circ}\text{C}$	10			$\mu\text{s}$	
$P_{tot}$	Total power dissipation	$T_C=25^{\circ}\text{C}, T_{vj}=175^{\circ}\text{C}$	2420			W	
Characteristics Values							
Symbol	Item	Conditions	Values			Unit	
IGBT			Min.	Typ.	Max.		
$I_{CES}$	Collector-emitter cut-off current	$V_{CE}=1200\text{V}, V_{GE}=0\text{V}, T_{vj}=25^{\circ}\text{C}$	-	-	1	mA	
$I_{GES}$	Gate leakage current	$V_{CE}=0\text{V}, V_{GE}=20\text{V}, T_{vj}=25^{\circ}\text{C}$	-	-	250	nA	
$V_{GE(th)}$	Gate-emitter threshold voltage	$I_C=16\text{mA}, V_{CE}=V_{GE}, T_{vj}=25^{\circ}\text{C}$	5	5.78	7	V	
$V_{CESat}$	Collector-emitter saturation voltage	$I_C=450\text{A}$ $V_{GE}=15\text{V}$	$T_{vj}=25^{\circ}\text{C}$	-	2.04		2.4
			$T_{vj}=125^{\circ}\text{C}$	-	2.48		-
			$T_{vj}=150^{\circ}\text{C}$	-	2.59	-	
$C_{ies}$	Input capacitance	$V_{CE}=25\text{V}, V_{GE}=0\text{V}$ $f=1\text{MHz}, T_{vj}=25^{\circ}\text{C}$	-	31.1	-	nF	
$C_{oes}$	Output capacitance		-	1.4	-		
$C_{res}$	Reverse transfer capacitance		-	1.35	-		
$Q_G$	Gate charge	$V_{CC}=600\text{V}, I_C=450\text{A}, V_{GE}=15\text{V}$	-	2.16	-	$\mu\text{C}$	
$R_g$	Internal gate resistance	$T_{vj}=25^{\circ}\text{C}$	-	1.25	-	$\Omega$	

$t_{d(on)}$	Turn-on delay time	$V_{CC}=600V$ $I_C=450A$ $V_{GE}=\pm 15V$ $R_{G(on)}=5.1\ \Omega$ $R_{G(off)}=5.1\ \Omega$ Inductive load	$T_{vj}=25^\circ C$	-	203.8	-	ns	
			$T_{vj}=125^\circ C$	-	209.6	-		
			$T_{vj}=150^\circ C$	-	200.1	-		
$t_r$	Rise time		$T_{vj}=25^\circ C$	-	202.5	-		
			$T_{vj}=125^\circ C$	-	208.5	-		
			$T_{vj}=150^\circ C$	-	209.1	-		
$t_{d(off)}$	Turn-off delay time		$T_{vj}=25^\circ C$	-	649.1	-		
			$T_{vj}=125^\circ C$	-	713.6	-		
			$T_{vj}=150^\circ C$	-	724.8	-		
$t_f$	Fall time	$T_{vj}=25^\circ C$	-	98.5	-			
		$T_{vj}=125^\circ C$	-	129.6	-			
		$T_{vj}=150^\circ C$	-	174.4	-			
$E_{on}$	Turn-on energy (per pulse)	$V_{CC}=600V, I_C=450A$ $V_{GE}=\pm 15V,$ $R_{G(on)}R_{G(off)}=5.1\ \Omega$ $di/dt=2676A/\mu s$ $du/dt=5700V/\mu s$ Inductive load	$T_{vj}=25^\circ C$	-	88.4	-	mJ	
			$T_{vj}=125^\circ C$	-	118.5	-		
			$T_{vj}=150^\circ C$	-	127.7	-		
$E_{off}$	Turn-off energy (per pulse)		$T_{vj}=25^\circ C$	-	43.7	-		
			$T_{vj}=125^\circ C$	-	52.7	-		
			$T_{vj}=150^\circ C$	-	56.1	-		
SC data	Short-circuit current		$V_{CC}=600V, V_{GE}\leq 15V, T_{vj}=25^\circ C$ $V_{CES}\leq 1200V, t_p\leq 10\mu s$	-	2160	-		A
$R_{thJC}$	Thermal resistance, junction to case		per IGBT	-	-	0.062		K/W
$R_{thCH}$	Thermal resistance, case to heatsink		per IGBT/ $\lambda_{grease}=1W/(m\cdot K)$	-	0.031	-		K/W
$T_{vjop}$	Temperature under switching conditions		-40		150	$^\circ C$		

**Diode, Inverter**

**Maximum Rated Values**

Symbol	Item	Conditions	Rating	Unit
$V_{RRM}$	Repetitive peak reverse voltage	$T_{vj}=25^\circ C$	1200	V
$I_F$	Forward current, DC		450	A
$I_{FRM}$	Repetitive peak forward current	$t_p=1ms$	900	A
$I^2t$	$I^2t$ -value	$V_R=0V, t_p=10ms, T_{vj}=150^\circ C$	32000	$A^2s$

**Characteristic Values**

$V_F$	Continuous forward voltage	$I_F=450A$ $V_{GE}=0V$	$T_{vj}=25^\circ C$	-	1.82	2.6	V	
			$T_{vj}=125^\circ C$	-	1.59	-		
			$T_{vj}=150^\circ C$	-	1.53	-		
$I_{RM}$	Peak reverse recovery current		$T_{vj}=25^\circ C$	-	146.3	-	A	
			$T_{vj}=125^\circ C$	-	246.9	-		
			$T_{vj}=150^\circ C$	-	274.8	-		
$t_{rr}$	Reverse recovery time		$V_R=600V$ $I_F=450A$ $-di_F/dt=2950A/\mu s$ $V_{GE}=-15V$	$T_{vj}=25^\circ C$	-	172.2	-	ns
				$T_{vj}=125^\circ C$	-	698.7	-	
				$T_{vj}=150^\circ C$	-	761.9	-	
$Q_r$	Recovered charge	$T_{vj}=25^\circ C$		-	22.7	-	$\mu C$	
		$T_{vj}=125^\circ C$		-	71.8	-		
		$T_{vj}=150^\circ C$		-	89.3	-		

E <sub>rec</sub>	Reverse recovery energy		T <sub>vj</sub> =25°C	-	6.6	-	mJ
			T <sub>vj</sub> =125°C	-	19.2	-	
			T <sub>vj</sub> =150°C	-	29.2	-	
R <sub>thJC</sub>	Thermal resistance, junction to case	per diode	-	-	0.11	-	K/W
R <sub>thCH</sub>	Thermal resistance, case to heatsink	per diode/ λgrease=1W/(m·K)	-	0.055	-	-	K/W
T <sub>vjop</sub>	Temperature under switching conditions		-40		150		°C

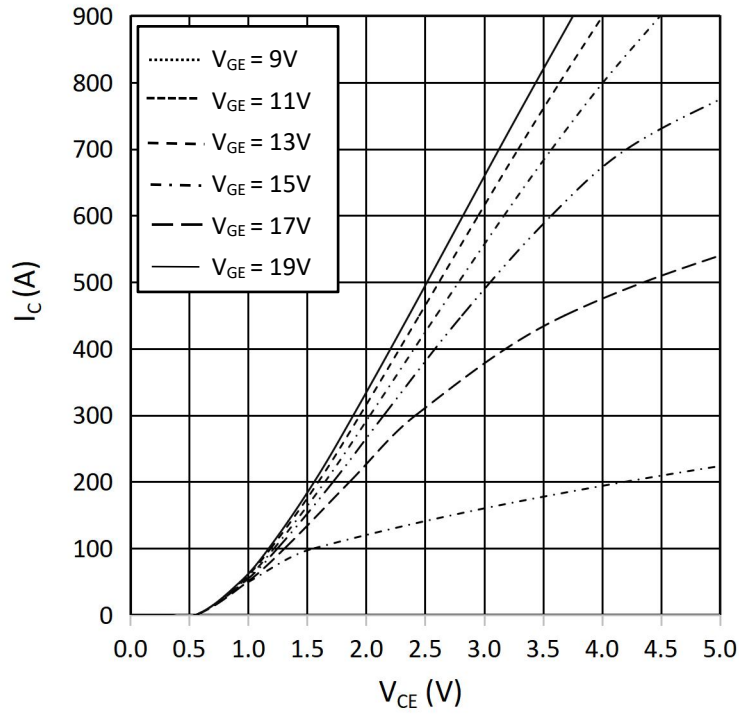
**Module**

Symbol	Item	Conditions	Rating			Unit
V <sub>ISOL</sub>	Isolation voltage	Terminals to baseplate, RMS, f=50Hz, t=1min	4000			V
-	Material of module baseplate	-	Cu			-
-	Internal isolation	Basic insulation(class 1, IEC 61140)	Al <sub>2</sub> O <sub>3</sub>			-
T <sub>stg</sub>	Storage temperature	-	-40~125			°C
Symbol	Item	Conditions	Values			Unit
			Min.	Typ.	Max.	
M	Mounting torque for module mounting	Screw M6	3.0	-	6.0	Nm
	Terminal connection torque	Screw M6	2.5	-	5.0	Nm
ds	Creepage distance	Terminal to terminal	-	23	-	mm
		Terminal to base plate	-	29	-	
da	Clearance	Terminal to terminal	-	11	-	mm
		Terminal to base plate	-	23	-	
m	Weight	-	-	320	-	g

**output characteristic IGBT, Inverter (typical)**

$I_C = f(V_{CE})$

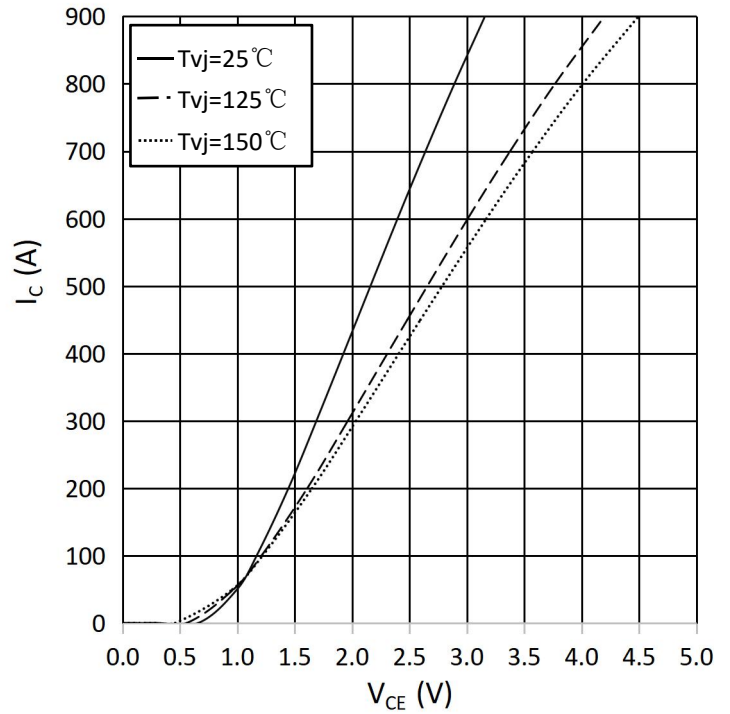
$T_{vj} = 150^\circ\text{C}$



**output characteristic IGBT, Inverter (typical)**

$I_C = f(V_{CE})$

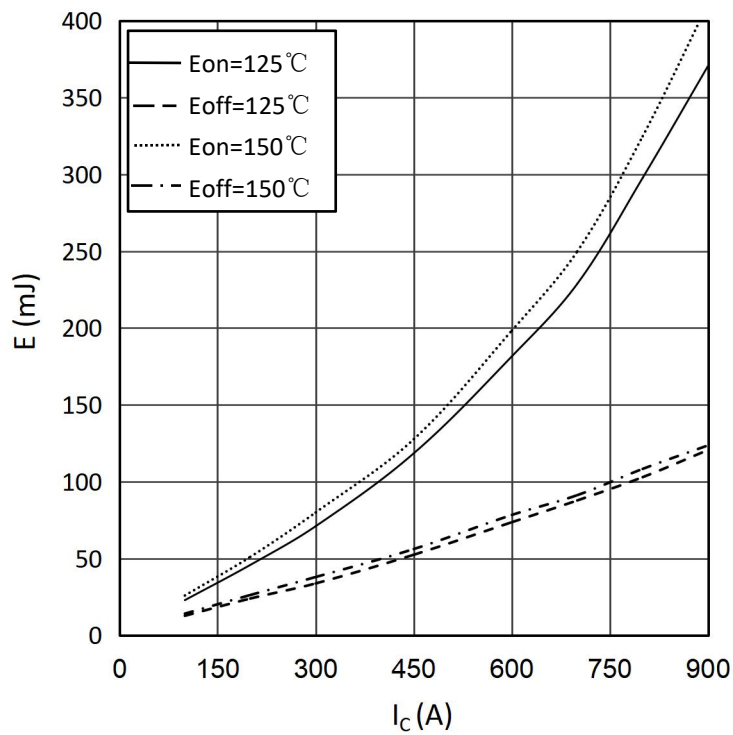
$V_{GE} = 15\text{ V}$



**switching losses IGBT, Inverter (typical)**

$E_{on} = f(I_C), E_{off} = f(I_C)$

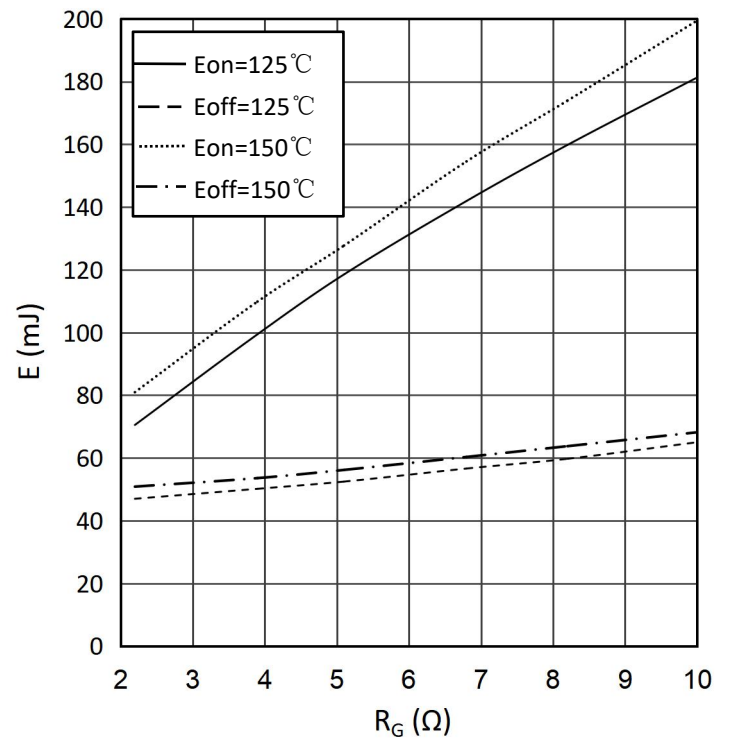
$V_{GE} = \pm 15\text{V}, R_{Gon} = 5.1\Omega, R_{Goff} = 5.1\Omega, V_{CE} = 600\text{V}$



**switching losses IGBT, Inverter (typical)**

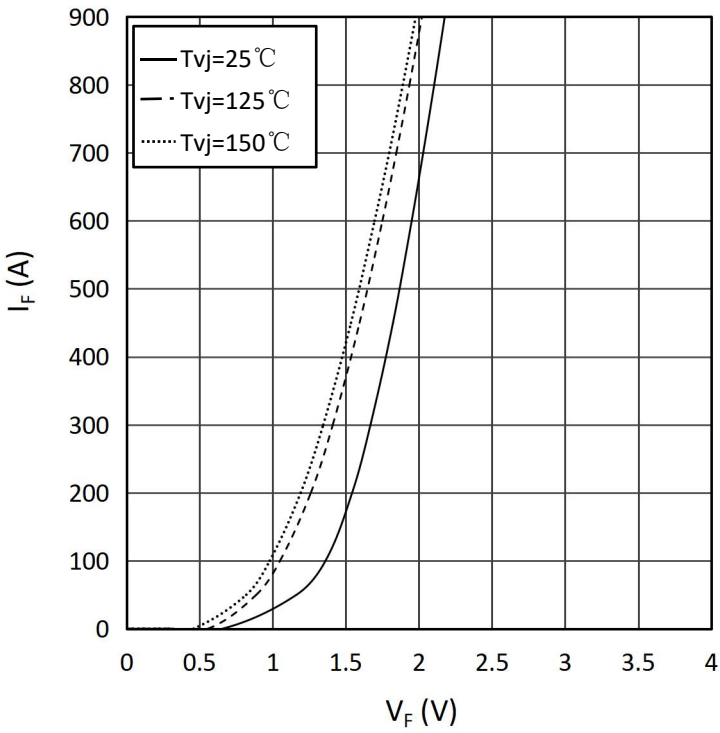
$E_{on} = f(R_G), E_{off} = f(R_G)$

$V_{GE} = \pm 15\text{V}, I_C = 450\text{A}, V_{CE} = 600\text{V}$



**forward characteristic of Diode, Inverter (typical)**

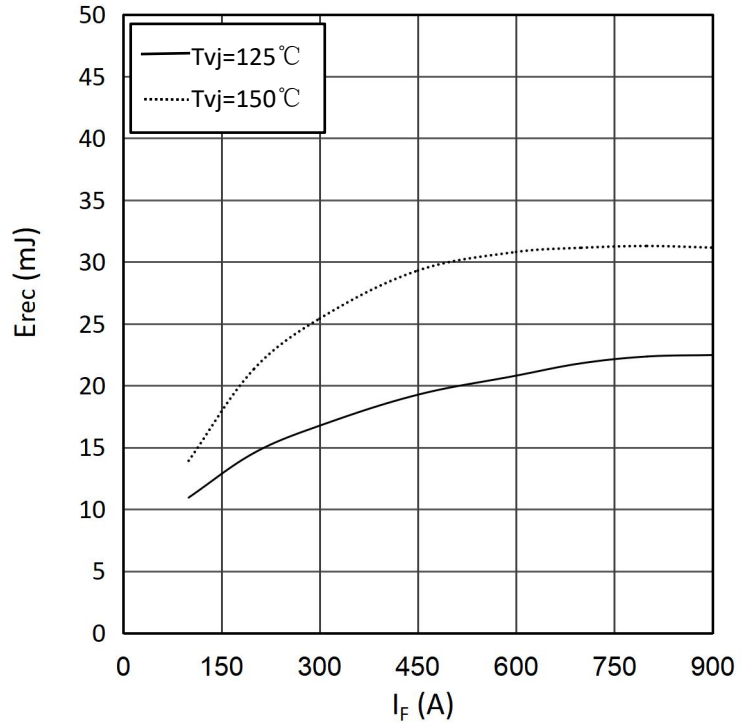
$I_F = f(V_F)$



**switching losses Diode, Inverter (typical)**

$E_{rec} = f(I_F)$

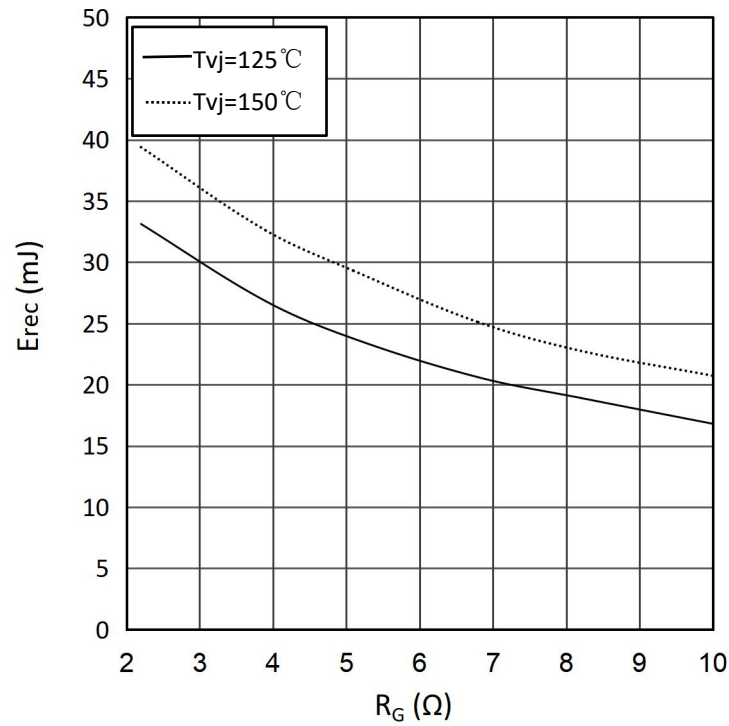
$R_{Gon}=5.1\Omega, V_{CE}=600V$



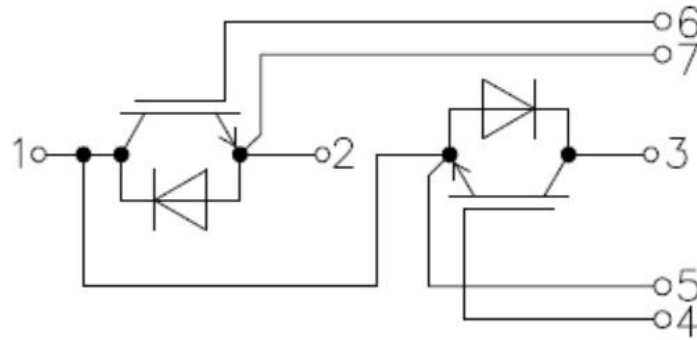
**switching losses Diode, Inverter (typical)**

$E_{rec} = f(R_G)$

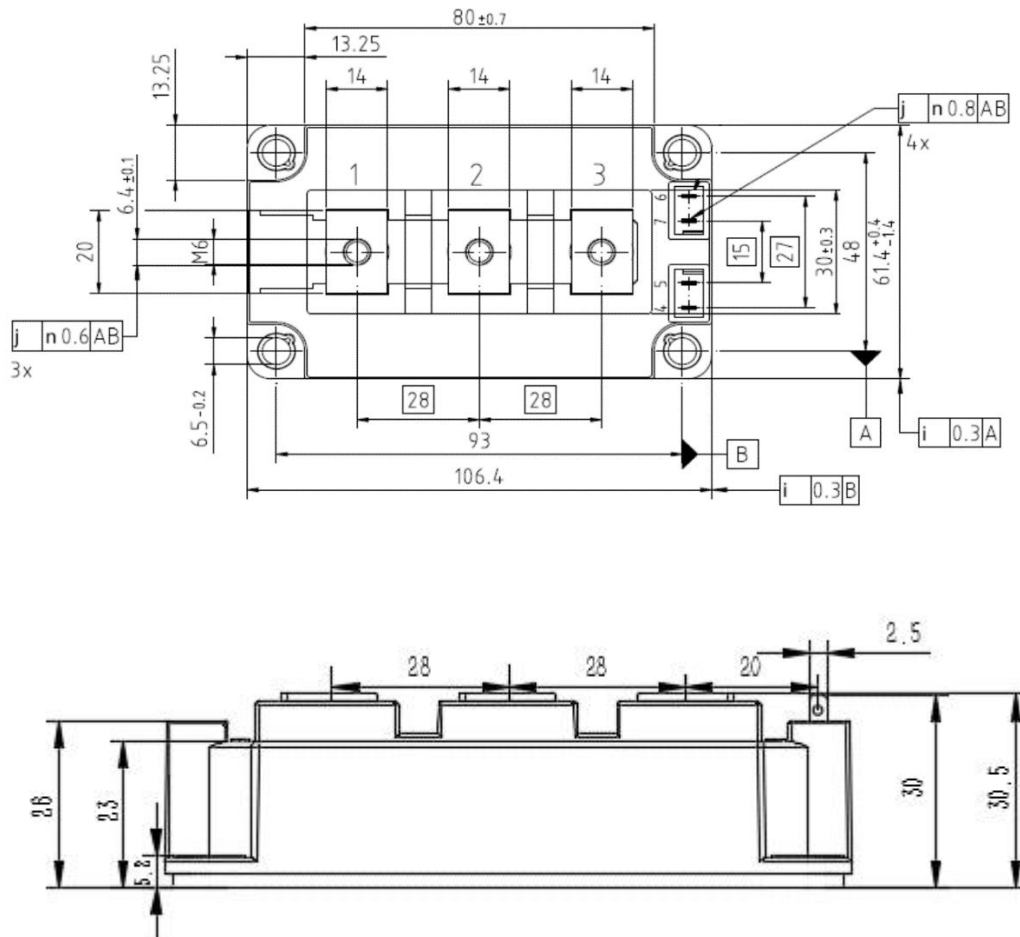
$I_F=450A, V_{CE}=600V$



Circuit diagram headline



Package outlines (Unit: mm)



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